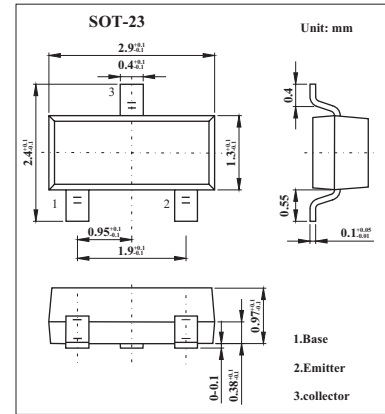


NPN Transistor
BC846A,B/BC847A,B,C/BC848A,B,C

■ Features

- Ideally suited for automatic insertion
- For Switching and AF Amplifier Applications



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-Base Voltage	BC846	80	V
	BC847	50	
	BC848	30	
Collector-Emitter Voltage	BC846	65	V
	BC847	45	
	BC848	30	
Emitter-Base Voltage	VEBO	6	V
Collector Current -Continuous	IC	0.1	A
Collector Power Dissipation	Pc	200	mW
Junction Temperature	TJ	150	°C
Storage Temperature	Tstg	-65 to +150	°C



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SMD Type

Transistors

BC846A,B/BC847A,B,C/BC848A,B,C

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit	
Collector-base breakdown voltage	BC846	$I_C = 10 \mu A, I_E = 0$	80			V	
	BC847		50				
	BC848		30				
Collector-emitter breakdown voltage	BC846	$I_C = 10mA, I_B = 0$	65			V	
	BC847		45				
	BC848		30				
Emitter-base Breakdown voltage	VEBO	$I_E = 10 \mu A, I_C = 0$	6			V	
Collector-base cutoff current	BC846	ICBO	$V_{CB} = 70 V, I_E = 0$			0.1	μA
	BC847		$V_{CB} = 50 V, I_E = 0$				
	BC848		$V_{CB} = 30 V, I_E = 0$				
Collector-emitter cutoff current	BC846	ICEO	$V_{CE} = 70V, I_B = 0$			0.1	μA
	BC847		$V_{CE} = 50V, I_B = 0$				
	BC848		$V_{CE} = 30V, I_B = 0$				
Emitter-base cutoff current	IEBO	$V_{EB} = 5 V, I_C = 0$			0.1	μA	
DC current gain	BC846A,847A,848A	hFE	$V_{CE} = 5 V, I_C = 2 mA$	110		220	
	BC846B,847B,848B			200		450	
	BC847C,848C			420		800	
Collector-emitter saturation voltage	VCE(sat)	$I_C = 100 mA, I_B = 5mA$			0.5	V	
Base-emitter saturation voltage	VBE(sat)	$I_C = 100 mA, I_B = 5mA$			1.1	V	
Collector output capacitance	Cob	$V_{CB}=10V, f=1MHz$			4.5	pF	
Transition frequency	f _T	$V_{CE} = 5 V, I_C = 10 mA, f = 100 MHz$	100			MHz	

■ Marking

NO.	BC846A	BC846B
Marking	1A	1B

NO.	BC847A	BC847B	BC847C
Marking	1E	1F	1G

NO.	BC848A	BC848B	BC848C
Marking	1J	1K	1L



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SMD Type Transistors

BC846A,B/BC847A,B,C/BC848A,B,C

Typical Characteristics

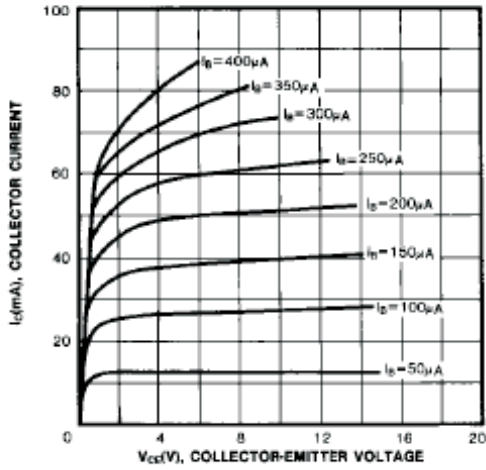


Fig.1 Static Characteristic

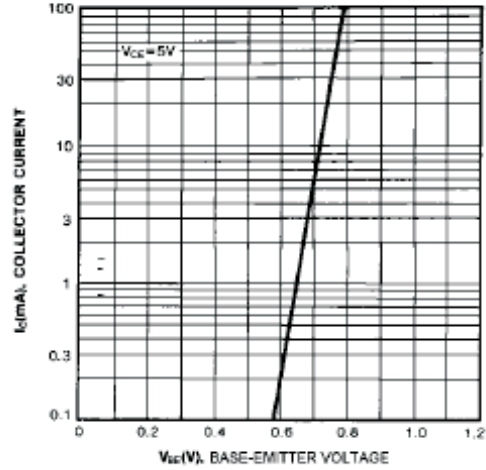


Fig.2 Transfer Characteristic

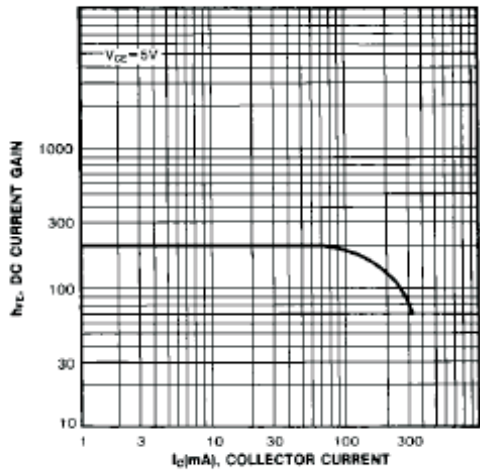


Fig.3 DC Current Gain

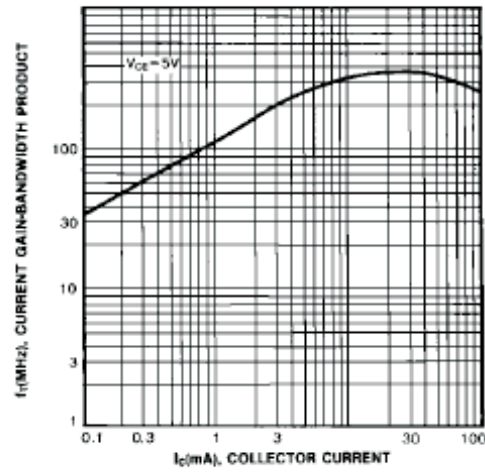


Fig.4 Current Gain Bandwidth Product

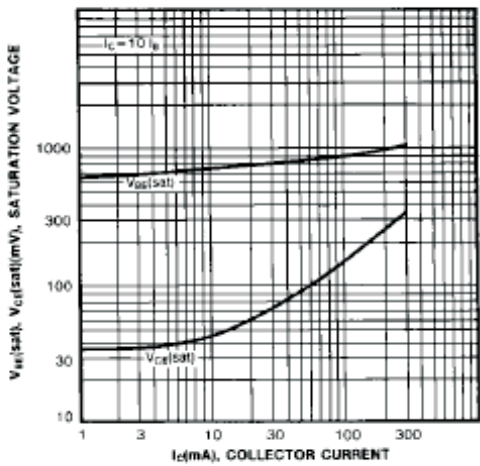


Fig.5 Base Emitter Saturation Voltage

Collector Emitter Saturation Voltage

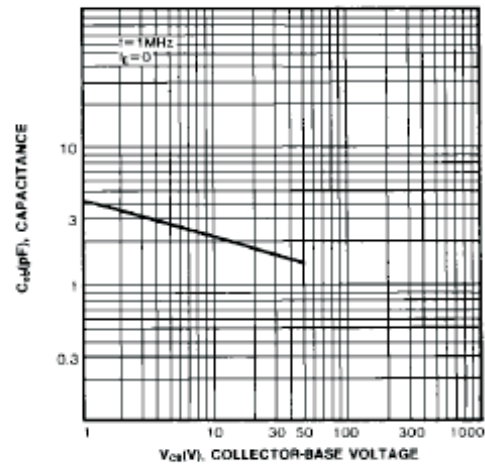


Fig.6 Output Capacitance